



30V N-Channel Enhancement Mode MOSFET

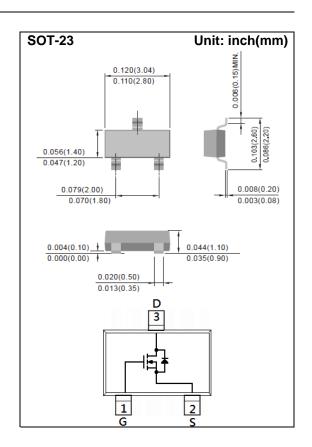
Voltage 30 V Current 4.4A

Features

- RDS(ON), VGS@10V, ID@4.4A<48mΩ
- RDS(ON) , VGS@4.5V, ID@2.8A<70mΩ
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A06



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	4.4	Α
Pulsed Drain Current		I _{DM}	17.6	Α
Power Dissipation	T _a =25°C	P_{D}	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ hetaJA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.37	2.1	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4.4A	-	35	48	mΩ		
		V _{GS} =4.5V, I _D =2.8A	-	51	70			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	0.01	1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA		
Dynamic								
Total Gate Charge	Q_g	V _{DS} =15V, I _D =4.4A, V _{GS} =10V ^(Note 1,2)	-	5.8	-	nC		
Gate-Source Charge	Q_gs		-	1	-			
Gate-Drain Charge	Q_gd		-	1	-			
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	235	-	pF		
Output Capacitance	Coss		-	36	-			
Reverse Transfer Capacitance	Crss		-	24	-			
Switching								
Turn-On Delay Time	td _(on)	\/ -45\/ -4.44	-	3	-			
Turn-On Rise Time	tr	V_{DD} =15V, I_{D} =4.4A, V_{GS} =10V, R_{G} =6 Ω (Note 1.2)	-	39	-	ns		
Turn-Off Delay Time	td _(off)		-	23	-			
Turn-Off Fall Time	tf		-	28	-			
Drain-Source Diode								
Maximum Continuous Drain-Source				-	1.5	Α		
Diode Forward Current	I _S							
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.77	1.2	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

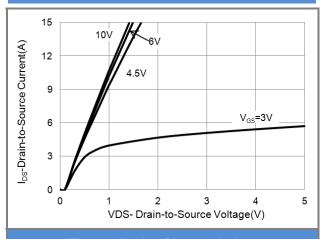


Fig.1 On-Region Characteristics

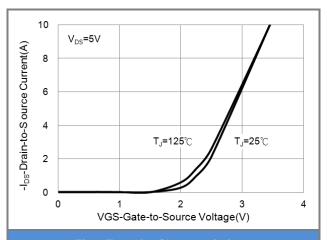


Fig.2 Transfer Characteristics

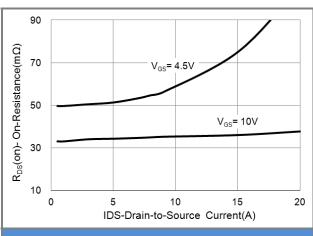


Fig.3 On-Resistance vs. Drain Current

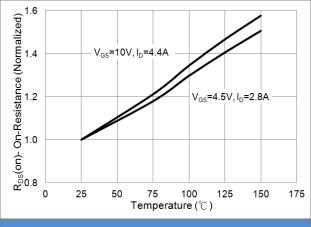


Fig.4 On-Resistance vs. Junction temperature

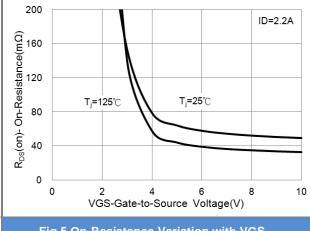


Fig.5 On-Resistance Variation with VGS.

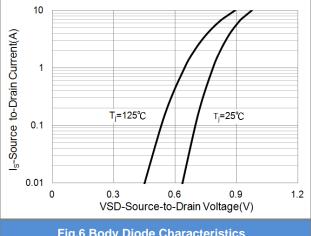


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

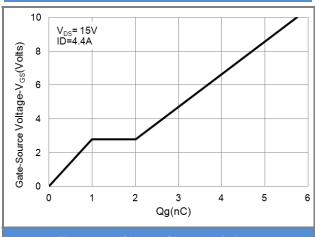


Fig.7 Gate-Charge Characteristics

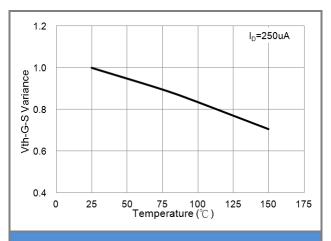


Fig.8 Threshold Voltage Variation with Temperature.

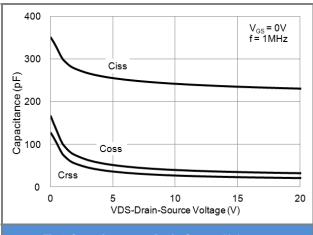


Fig.9 Capacitance vs. Drain-Source Voltage.

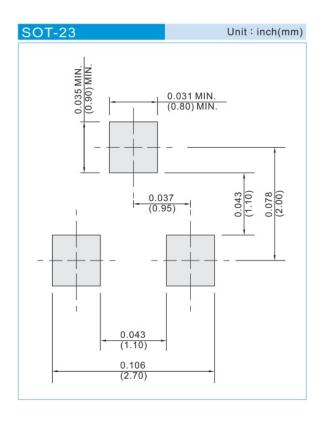




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3406_R1_00001	SOT-23	3K pcs / 7" reel	A06	Halogen free
PJA3406_R2_00001	SOT-23	12K pcs / 13" reel	A06	Halogen free

MOUNTING PAD LAYOUT







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